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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
09/839,436	04/20/2001	Clark TC. Nguyen	UOM0233PUS	3445
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David R. Syrowik			EXAMINER	
Brooks & Kushman P.C.			DOUGHERTY, THOMAS M	
22nd Floor 1000 Town Center			ART UNIT	PAPER NUMBER
Southfield, MI	48075-1351		2834	
		DATE MAILED: 03/27/2002		

Please find below and/or attached an Office communication concerning this application or proceeding.

_		Application No.	Applicant(s)
•	•	09/839,436	NGUYEN, CLARK TC.
	Office Action Summary	Examiner	Art Unit
		Thomas M. Dougherty	2834
	The MAILING DATE of this communication ap		
THE I	ORTENED STATUTORY PERIOD FOR REPLEMAILING DATE OF THIS COMMUNICATION. Issions of time may be available under the provisions of 37 CFR 1. SIX (6) MONTHS from the mailing date of this communication.	-	, ,
- If NO - Failu - Any r	period for reply specified above is less than thirty (30) days, a reperiod for reply is specified above, the maximum statutory period re to reply within the set or extended period for reply will, by statutely received by the Office later than three months after the mailing department adjustment. See 37 CFR 1.704(b).	will apply and will expire SIX (6) MONTHS from the cause the application to become ABANDO	om the mailing date of this communication. NED (35 U.S.C. § 133).
1)⊠	Responsive to communication(s) filed on 04.	<u> 20/01</u> .	
2a)□	This action is FINAL . 2b)⊠ T	his action is non-final.	
3)□	Since this application is in condition for allow closed in accordance with the practice unde		
Dispositi	on of Claims		
4) 🛛	Claim(s) 1-25 is/are pending in the application	n.	
	4a) Of the above claim(s) is/are withdra	wn from consideration.	
5)	Claim(s) is/are allowed.		
6)⊠	Claim(s) <u>1-25</u> is/are rejected.		
7)	Claim(s) is/are objected to.		
8)□	Claim(s) are subject to restriction and/	or election requirement.	
pplicati	on Papers		
9)[The specification is objected to by the Examin	er.	
10)🛛 -	The drawing(s) filed on 20 April 2001 is/are: a	☐ accepted or b)☐ objected to by	y the Examiner.
	Applicant may not request that any objection to the	ne drawing(s) be held in abeyance.	See 37 CFR 1.85(a).
11)	The proposed drawing correction filed on	_ is: a)□ approved b)□ disapp	proved by the Examiner.
	If approved, corrected drawings are required in re	eply to this Office action.	
12)	Γhe oath or declaration is objected to by the Ε	xaminer.	
riority u	ınder 35 U.S.C. §§ 119 and 120		
13)	Acknowledgment is made of a claim for foreig	n priority under 35 U.S.C. § 119	(a)-(d) or (f).
a)[☐ All b)☐ Some * c)☐ None of:		
	1. Certified copies of the priority documer	ts have been received.	
	2. Certified copies of the priority documer	ts have been received in Applic	ation No
* 5	3. Copies of the certified copies of the pricapplication from the International Bee the attached detailed Office action for a lis	ureau (PCT Rule 17.2(a)).	· ·
	cknowledgment is made of a claim for domes	•	
a	The translation of the foreign language practice. Acknowledgment is made of a claim for domes	ovisional application has been r	eceived.
ttachmen		30	
2) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Information	ary (PTO-413) Paper No(s) al Patent Application (PTO-152)
Patent and Tr O-326 (Re	ademark Office v. 04-01) Office A	ction Summary	Part of Paper No. 3

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Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 5- are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention. In claim 5, the "plurality of intercoupled micromechanical elements including a resonator" does not describe a coherent structure. There is no indication to a routineer in the art what these other micromechanical elements, not including the resonator, could be. Additionally, there is no description of the resonator itself. There are no metes or bounds as to what this description entails. Additionally, claim 5 doesn't effectively describe a structure such that the goals of the invention that are listed can be achieved. For example, what dimensions are required so "that the resonator is isolated from the support structure during resonator vibration wherein energy losses to the substrate are substantially eliminated and wherein the apparatus is a high-Q apparatus". What exactly are "a silicon-based filter apparatus" and "a diamond-based filter apparatus"? What does this language mean in the context of the claim. Are the resonator components these materials? Is the substrate one of these materials? Based on the claim language, this is indefinite.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

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A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 5, 7-9, 11, 13, 15 and 19-25, as best understood, are rejected under 35 U.S.C. 102(b) as being anticipated by Nguyen et al. article "Design and Performance of CMOS Micromechanical Resonator Oscillators". Said article shows a method for filtering (see col. 2, line 5, where its use for filtering applications is acknowledged) signals to obtain a desired passband of frequencies, the method comprising: providing (see for example fig. 4) a micromechanical filter apparatus including a micromechanical resonator having a fundamental resonant mode formed on a substrate and a support structure anchored to the substrate to support the resonator above the substrate; and vibrating the resonator so that the apparatus passes a desired frequency range of signals while substantially attenuating signals outside the desired frequency range, wherein the support structure is attached to the resonator so that the resonator is isolated from the support structure during resonator vibration. His elements are intercoupled, is a high-Q apparatus (see abstract). His signals are RF signals and is a bandpass filter apparatus and the support structure includes at least one beam. The apparatus is a silicon based filter apparatus as that is best understood (see fig. 2 substrate). There is at least one output electrode (see fig. 7). The support structure includes a plurality of beams. The plurality of intercoupled micromechanical elements includes a pair of intercoupled end resonators. And the support structure supports the end resonators above the substrate. The support structure supports the end resonators above the substrate. There are inner resonators intercoupled to the end resonators.

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Recitiation of the operations modes are regarded as goals of the invention and not descriptive of a further limiting of structure, as such, the goals carry no patentable weight.

Claims 1-13 and 15-25, as best understood, are rejected under 35 U.S.C. 102(b) as being anticipated by Lin et al. (US 5,537,083). Lin shows (fig. 6A) a method for filtering signals to obtain a desired passband of frequencies, the method comprising: providing (see for example fig. 6A) a micromechanical filter (see ABSTRACT) apparatus including a micromechanical resonator having a fundamental resonant mode formed on a substrate (see claim 1) and a support structure anchored (50) to the substrate to support the resonator above the substrate; and vibrating the resonator so that the apparatus passes a desired frequency range of signals while substantially attenuating signals outside the desired frequency range, wherein the support structure is attached to the resonator so that the resonator is isolated from the support structure during resonator vibration (note in the summary, vibration is free and additionally in claim 1 that "said first and second rigid masses are mechanically coupled but able to move independently). His elements are intercoupled (as just noted in reference to claim 1). The step of vibrating includes forcing different portions of the resonator to move in opposite directions at the same time so that the resonator vibrates in a resonant mode, m, higher than the fundamental resonant mode wherein the resonator has m+1 nodal points. Note that any time anything vibrates at a frequency and has a plurality of nodes, it necessarily is vibrating at a frequency higher than its fundamental resonant frequency. As the device is intended for radio filtering, a fairly broad range of frequencies is

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inherently applicable as input. The micromechanical filter apparatus includes a plurality of input electrodes (fig. 6A) spaced along the resonator to allow electrostatic excitation of the resonator and wherein the step of forcing includes the steps of applying an inphase signal (V_i) to one of the input electrode to deflect a first portion of the resonator in a first direction and applying an out-of-phase signal (output of 215) to another input electrode to deflect a second portion of the resonator in a second direction opposite the first direction to force the resonator in to a correct mode shape. Regarding the citation of the structural features of spacers in the method for filtering claims, this feature does not contribute to the further limitation of the methodology and therefore carries no patentable weight. His apparatus, as it meets the claimed structural features, is thus a high-Q apparatus. As noted the resonator is free to vibrate. This description means that the support structure is attached to the resonator at at least one nodal point of the resonator. His signals are RF signals and is a bandpass filter apparatus and the support structure includes at least one beam. The apparatus is a silicon based filter apparatus as that is best understood (see col. 2, II. 18-20). The device further comprises (see fig. 7S for example) at least one spacer (vertical component of 450) extending between the resonator (450) and the substrate at a nodal point (as noted this is inherent as the device freely vibrates, thus nodal connection must take place, otherwise the vibration is not free) of the resonator wherein the size of the gap is based on the height of the at least one spacer during pull down of the resonator. There is at least one output electrode (from 305 and 310). The support structure includes a plurality of beams and the resonator includes a plurality of nodal points and wherein

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each of the beams is attached to the resonator at one of the nodal points of the resonator so that the resonator sees substantially no resistance (note that the device vibrates freely) to transverse or torsional motion from the support structure. A pair of balanced input electrodes are formed on the substrate (required for figs. 6Q and 6B) to allow electrostatic excitation of the resonator. A pair of balanced output electrodes (required for figs. 6A and 6B) are formed on the substrate to sense the output of the apparatus. The support structure includes a plurality of beams. The plurality of intercoupled micromechanical elements includes a pair of intercoupled end resonators. And the support structure supports the end resonators above the substrate. The support structure supports the end resonators above the substrate. There are inner resonators intercoupled to the end resonators. Recitation of the operations modes in the Applicants' claims 24 and 25 are regarded as goals of the invention and not descriptive of a further limiting of structure, as such, the goals carry no patentable weight.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 14 is rejected under 35 U.S.C. 103(a) as being unpatentable over Lin et al. (US 5,537,083) in view of either ordinary skill in the art or Ella (US 6,278,342). Given

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the invention of Lin et al. as noted above they fail to show a diamond-based filter

apparatus as that description is best understood. It would have been obvious to one

having ordinary skill in the art at the time the invention was made to show a diamond-

based filter apparatus in the invention of Lin et al., since it has been held to be within

the general skill of a worker in the art to select a known material on the basis of its

suitability for the intended use as a matter of obvious design choice. In re Leshin, 125

USPQ 416. To wit, see col. 9, lines 11-22 where Ella notes interchangeability of

materials in a micromechanical filter device.

Conclusion

The prior art made of record and not relied upon is considered pertinent to

applicant's disclosure. Lin et al. show similar structures and operations to those claimed

by the Applicants and noted above in USP 5,589,082. Other patents made of record

show aspects of the claimed invention.

Direct inquiry concerning this action to Examiner Dougherty at (703) 308-

1628.

March 18, 2002